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### FAIRCHILD

SEMICONDUCTOR®

# FGAF40N60UFD

### Ultrafast IGBT

### **General Description**

Fairchild's UFD series of Insulated Gate Bipolar Transistors (IGBTs) provides low conduction and switching losses. The UFD series is designed for applications such as motor control and general inverters where high speed switching is a required feature.

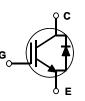
### Features

- High speed switching
- Low saturation voltage :  $V_{CE(sat)} = 2.3 \text{ V} @ I_C = 20 \text{ A}$
- High input impedance
- CO-PAK, IGBT with FRD :  $t_{rr} = 50$ ns (typ.)

### Applications

AC & DC motor controls, general purpose inverters, robotics, and servo controls.





G C E

### Absolute Maximum Ratings T<sub>c</sub> = 25°C unless otherwise noted

Symbol	Description		FGAF40N60UFD	Units
V <sub>CES</sub>	Collector-Emitter Voltage		600	V
V <sub>GES</sub>	Gate-Emitter Voltage		± 20	V
	Collector Current	@ T <sub>C</sub> = 25°C	40	A
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 100°C	20	A
I <sub>CM (1)</sub>	Pulsed Collector Current		160	A
IF	Diode Continuous Forward Current	@ T <sub>C</sub> = 100°C	15	A
I <sub>FM</sub>	Diode Maximum Forward Current		160	A
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	100	W
	Maximum Power Dissipation	@ T <sub>C</sub> = 100°C	40	W
TJ	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for Soldering Purposes, 1/8" from Case for 5 Seconds		300	°C

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Units
R <sub>0JC</sub> (IGBT)	Thermal Resistance, Junction-to-Case		1.2	°C/W
R <sub>0JC</sub> (DIODE)	DE) Thermal Resistance, Junction-to-Case		2.6	°C/W
$R_{\theta JA}$	DJA Thermal Resistance, Junction-to-Ambient		40	°C/W

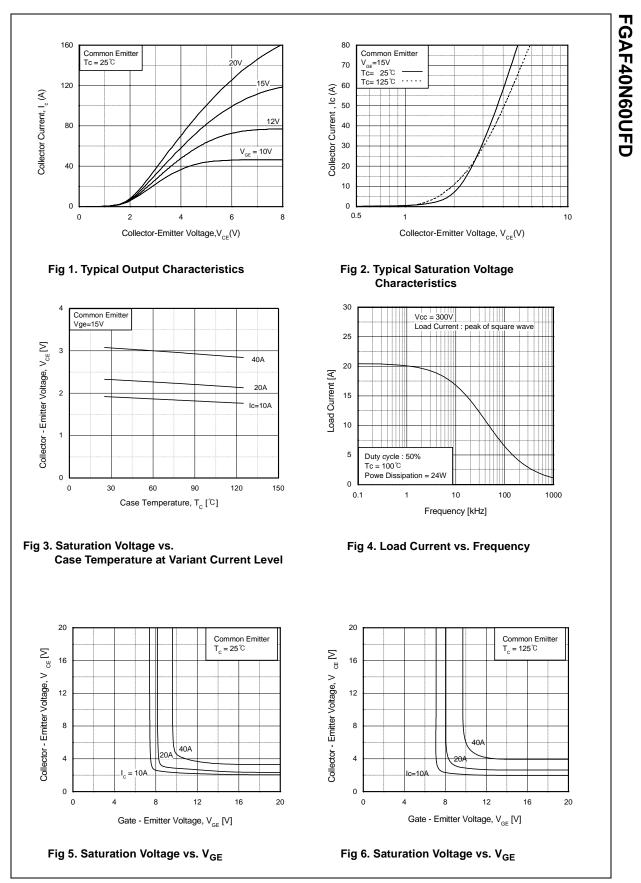
IGBT

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Cha	racteristics					
BV <sub>CES</sub>	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250uA$	600			V
$\Delta B_{VCES}/\Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$		0.6		V/∘C
ICES	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			250	uA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
On Cha	racteristics					
V <sub>GE(th)</sub>	G-E Threshold Voltage	$I_{C}$ = 20mA, $V_{CE}$ = $V_{GE}$	3.5	5.1	6.5	V
	Collector to Emitter	$I_{\rm C} = 20$ A, $V_{\rm GE} = 15$ V		2.3	3.0	V
V <sub>CE(sat)</sub>	Saturation Voltage	$I_{\rm C} = 40$ A, $V_{\rm GE} = 15$ V		3.1		V
•	c Characteristics	Τ	1		1	
C <sub>ies</sub>	Input Capacitance	V <sub>CE</sub> = 30V, V <sub>GE</sub> = 0V,		1075		pF
C <sub>oes</sub>	Output Capacitance	f = 1MHz		170		pF
C <sub>res</sub>	Reverse Transfer Capacitance			50		pF
Switchi	ng Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			15		ns
t <sub>r</sub>	Rise Time			30		ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, \text{ I}_{C} = 20 \text{ A},$		65	130	ns
t <sub>f</sub>	Fall Time	$R_{G} = 10\Omega, V_{GE} = 15V,$		35	100	ns
Eon	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 25°C		470		uJ
E <sub>off</sub>	Turn-Off Switching Loss			130		uJ
E <sub>ts</sub>	Total Switching Loss			600	1000	uJ
t <sub>d(on)</sub>	Turn-On Delay Time			30		ns
t <sub>r</sub>	Rise Time			37		ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{CC} = 300 \text{ V}, I_{C} = 20\text{A},$		110	200	ns
t <sub>f</sub>	Fall Time	$R_{G} = 10\Omega, V_{GE} = 15V,$		80	250	ns
E <sub>on</sub>	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 125°C		500		uJ
	Turn-Off Switching Loss			310		uJ
	Total Switching Loop			810	1200	uJ
E <sub>off</sub>	Total Switching Loss			77	150	nC
E <sub>off</sub> E <sub>ts</sub>	Total Gate Charge	1/2 = 200 1/1 = 200				
E <sub>off</sub> E <sub>ts</sub> Q <sub>g</sub>	•	$V_{CE} = 300 \text{ V}, I_{C} = 20\text{A},$		20	30	nC
E <sub>off</sub> E <sub>ts</sub> Q <sub>g</sub> Q <sub>ge</sub> Q <sub>gc</sub>	Total Gate Charge	$V_{CE} = 300 \text{ V}, I_{C} = 20\text{A},$ $V_{GE} = 15\text{V}$		20 25	30 40	nC nC

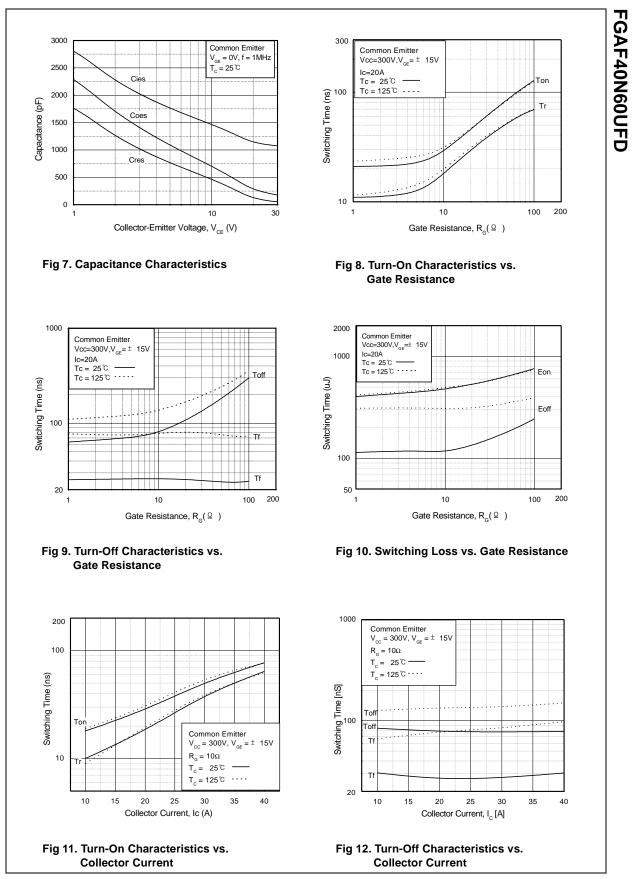
### Electrical Characteristics of DIODE $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
V	Diode Forward Voltage	I <sub>F</sub> = 15A	$T_{C} = 25^{\circ}C$		1.4	1.7	V
V <sub>FM</sub> Diode Fo	Didde Forward Voltage	$I_F = 15A$	$T_{C} = 100^{\circ}C$		1.3		v
+	Diode Reverse Recovery Time		$T_{C} = 25^{\circ}C$		50	95	ns
t <sub>rr</sub>	Didde Reverse Recovery Time	T	$T_{C} = 100^{\circ}C$		74		115
1	Diode Peak Reverse Recovery	I <sub>F</sub> = 15A,	$T_{C} = 25^{\circ}C$		4.5	6.0	Α
Irr	Current	di/dt = 200A/us	$T_{C} = 100^{\circ}C$		6.5		
Q <sub>rr</sub>	Diode Reverse Recovery Charge		$T_{C} = 25^{\circ}C$		80	180	nC
			$T_{C} = 100^{\circ}C$		220		

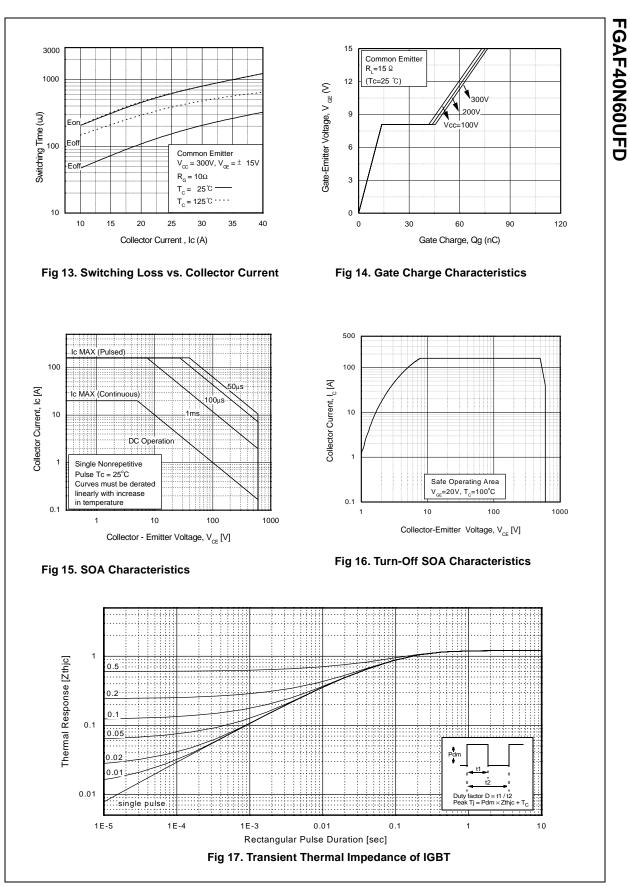
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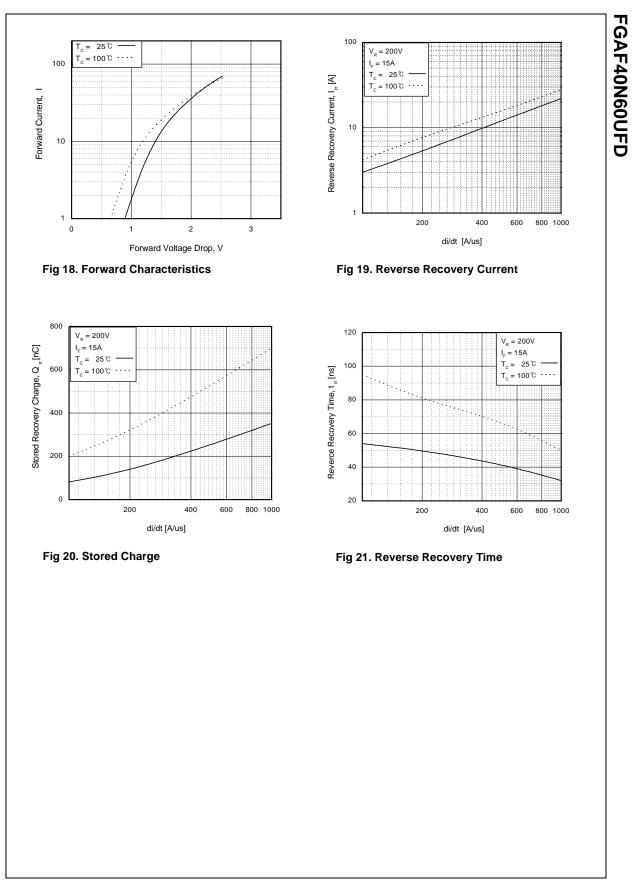


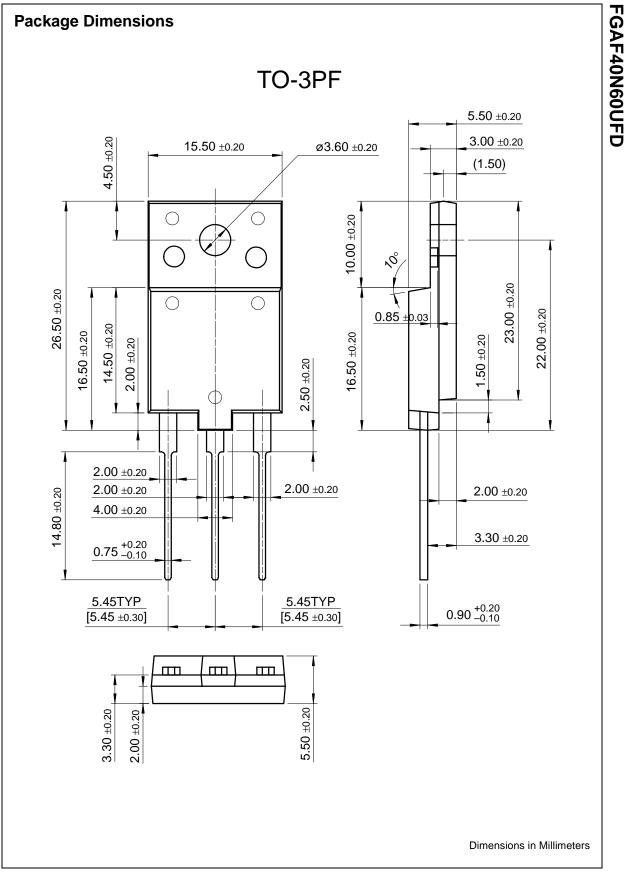
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